

Peak pulse voltage ($T_j=25$; non-repetitive, off-state; FIG.8)	V_{pp}	3	kV
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ELECTRICAL CHARACTERISTICS (unless otherwise specified)

Symbol	Conditions	Unit	Value	Unit
I_{GT}	$V_D=12V R_L=33$	-	MAX.	10
V_{GT}		-	MAX.	1
V_{GD}	$V_D=V_{DRM} T_j=125$ $R_L=3.3k$	-	MIN.	0.2
I_L	$I_G=1.2I_{GT}$	-	MAX.	20
				35
I_H	$I_T=100mA$		MAX.	15
dV/dt	$V_D=540V$ Gate Open $T_j=125$		MIN.	500
(dI/dt)c	(dV/dt)c=10V/ μs , $T_j=125$		MIN.	2.5
t_{on}	$I_G=20mA I_A=200mA I_R=20mA$ $T_j=25$		TYP.	2.5
t_{off}				25

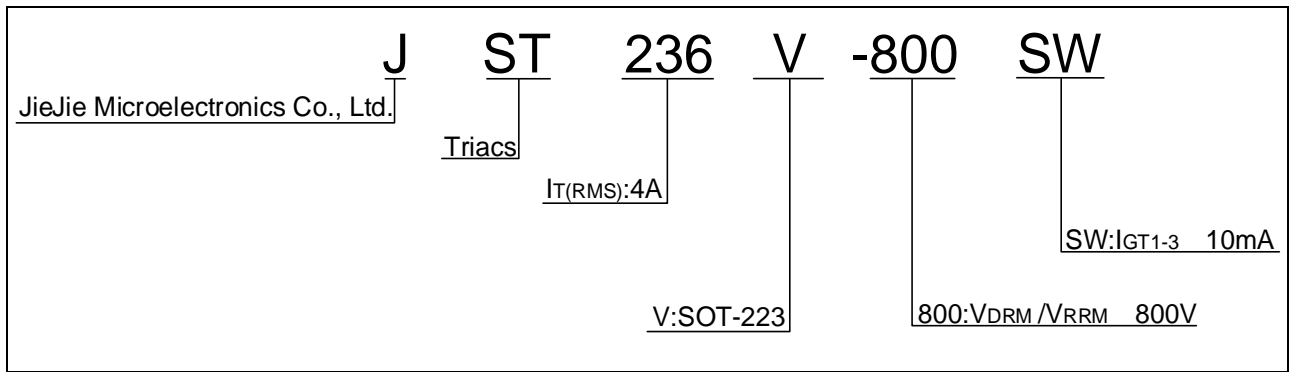
STATIC CHARACTERISTICS

Symbol	Conditions	Unit	Value	Unit
V_{TM}	$I_{TM}=5A t_p=380\mu s$ $T_j=25$		1.5	V
V_{TO}	Threshold voltage $T_j=125$		0.78	V
R_D	Dynamic resistance $T_j=125$		190	m
I_{DRM}	$V_D=V_{DRM} V_R=V_{RRM}$ $T_j=25$		5	μA
I_{RRM}		$T_j=125$	0.25	mA

THERMAL RESISTANCES

Symbol	Conditions	Unit	Value	Unit
$R_{th(j-c)}$	junction to case (AC)		17	/W
$R_{th(j-a)}$	junction to ambient (AC)		60	/W

ORDERING INFORMATION



MARKING

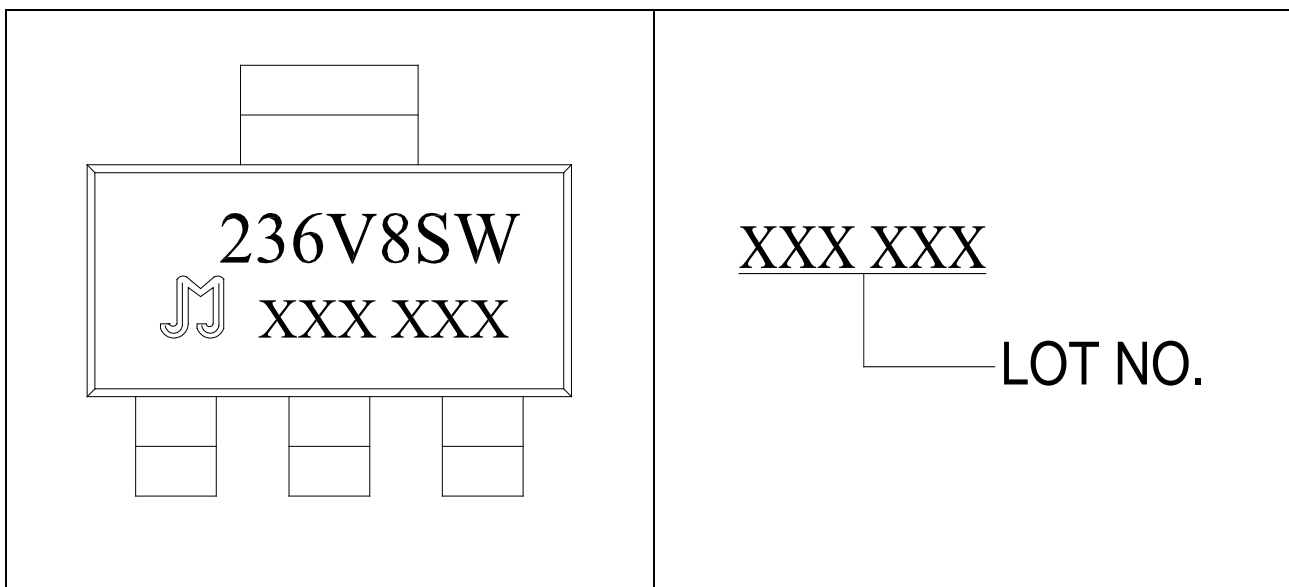


FIG.1: Maximum power dissipation versus RMS on-state current

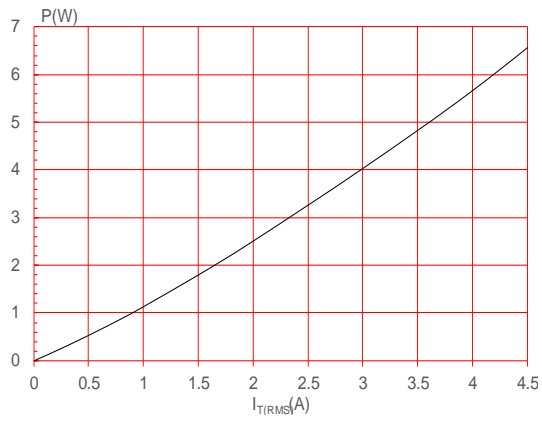


FIG.2: RMS on-state current versus case temperature

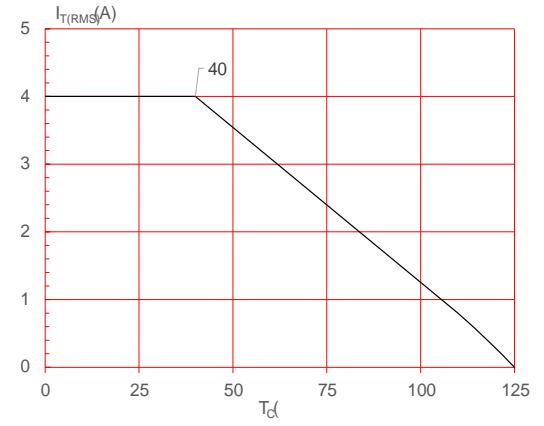


FIG.7: Relative variations of gate trigger current, holding current and latching current versus junction temperature

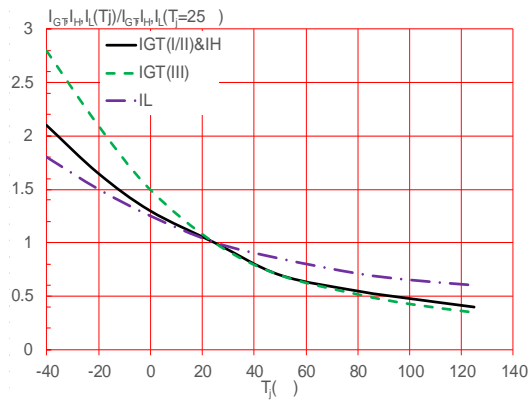
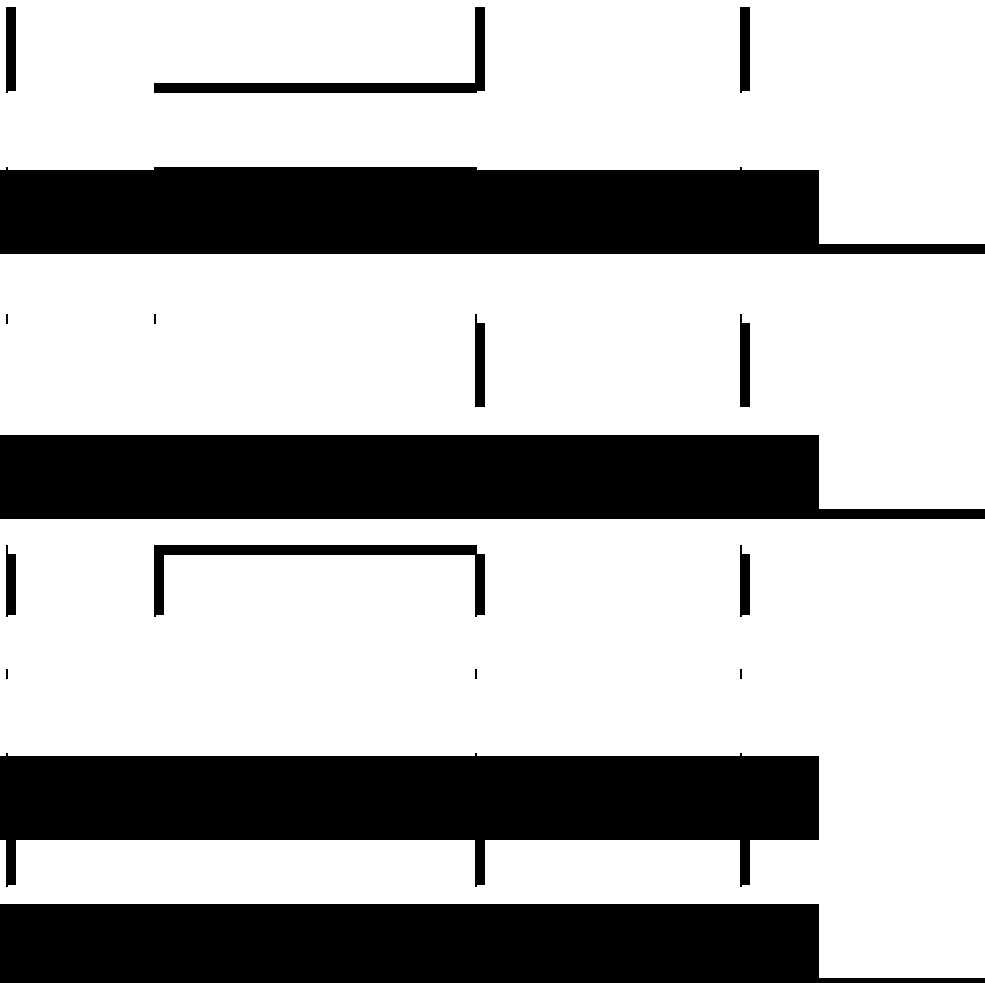
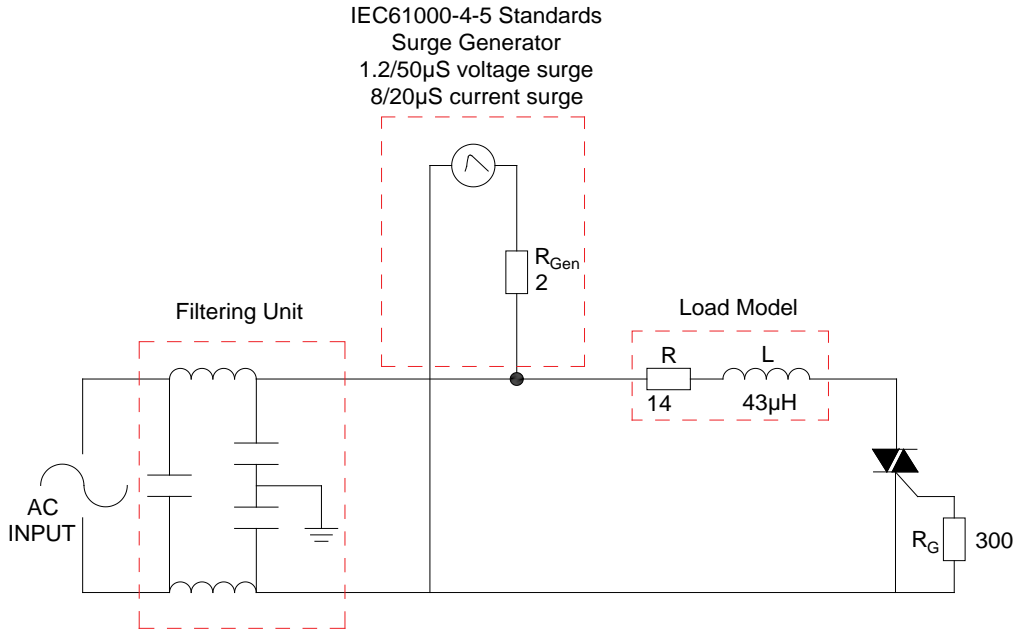


FIG.8 Test circuit for inductive and resistive loads to IEC-61000-4-5 standards



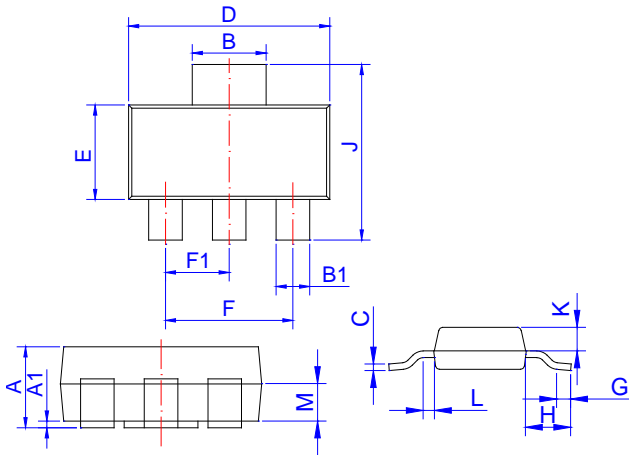
ORDERING INFORMATION

Order	V _{DRM} /V _{RRM} (V)	IGT(A _m)	P _g	Qty (p)	D _{th}
		- -			
JST236A800SW	800	10	SOT-223	4,000	T _g R _e

Revision

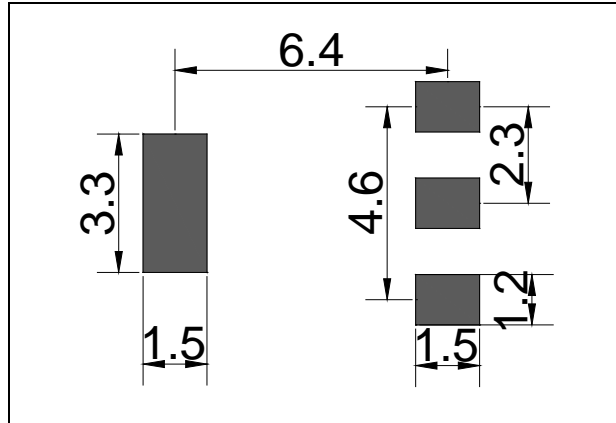
Date	Revision	Changes
Apr.11, 2025	A.1.0	Last updated

PACKAGE MECHANICAL DATA



Ref.	Dimensions					
	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	1.50	1.60	1.80	0.059	0.063	0.071
A1	0.01	0.06	0.10	0.001	0.002	0.004
B	2.90	3.00	3.10	0.114	0.118	0.122
B1	0.60	0.70	0.80	0.024	0.028	0.031
C	0.22	0.26	0.32	0.009	0.010	0.013
D	6.30	6.50	6.70	0.248	0.256	0.264
E	3.30	3.50	3.70	0.130	0.138	0.146
F	4.40		4.80	0.173		0.189
F1	2.20		2.40	0.087		0.094
G	0.50		1.00	0.020		0.039
H	1.50	1.75	2.00	0.059	0.069	0.079
J	6.70	7.00	7.30	0.264	0.276	0.287
K	0.80		1.00	0.031		0.039
L	0.40		0.80	0.016		0.031
M	0.75		0.95	0.030		0.037

FOOTPRINT SOT223 (dimensions in mm)



DELIVERY MODE

Dimensions

Ref.

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